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Band structure and charge carrier dynamics in (W,N)-codoped TiO₂ resolved by electrochemical impedance spectroscopy combined with UV-vis and EPR spectroscopies

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abstract

Semiconductor photocatalysis is on the verge of (probably) its most important deployment and boost since the pioneering paper of Fujishima and Honda in 1972. Photo-generation of unbound excitons, i.e. separated conduction band electrons and valence band positive holes, is the fundamental primary process triggering charge separation in solid semiconductors necessary to initiate their photocatalytic activity. Immediately after being generated, charge carriers can undergo processes like recombination, trapping in mid-band-gap states or, paramount for photocatalytic processes, transfer to species adsorbed on the solid semiconductor surface. In TiO₂ and doped TiO₂, interfacial charge transfers are the slowest amongst the primary processes; therefore, electron (and hole) transfer most likely occurs from single electron traps (i.e. involving radical species). We report here on an effective approach combining electrochemical impedance spectroscopy with other spectroscopic techniques such as UV-vis and electron paramagnetic resonance. This approach allows deriving important information about band structure and following electron dynamics triggered by photon absorption. The redox potentials of the band edges and the influence of the dopants on the band structure are elucidated by electro-chemical impedance spectroscopy combined with UV-vis spectroscopy. Electron dynamics are then studied using electron paramagnetic resonance spectroscopy, to elucidate the photochemical reactions at the basis of the photo-generated electron-hole pairs, and subsequent trapping and/or recombination. Results of a TiO₂ sample containing W and N as dopants (0.1 at.% of W) highlight a narrowing of the intrinsic band gap of about 0.12 eV. The semiconductor visible light photochemistry is driven by diamagnetic donor states [N_iO]_w and [N_iO]_w (formally NO³⁻), from which electrons can be excited to the conduction band, generating EPR active paramagnetic [N_iO][•] and [N_iO][•]_w states (formally NO²⁻). The formation of W⁵⁺ electron trapping states, energetically more favourable than Ti³⁺ electron trapping states, is also identified.

1. Introduction

Nitrogen doped TiO₂ is one of the most studied visible light photocatalysts. It was first reported by Sato in 1986 as NO_x doped titania [1] and in most cases it has shown improved visible light harvesting when compared to ordinary TiO₂ [1–11]. Despite the in-depth understanding regarding its photoactivity, major drawbacks are yet to be overcome. Charge compensation demands either an increase in oxygen vacancies or decrease in charge carrier (i.e. electrons given the intrinsic n-type character of TiO₂) density upon introduction of the p-dopant (i.e. N), which in turn reduces the overall efficiency of the catalyst [7,12]. Furthermore, Zhao et al. [13] showed that N doped TiO₂ could be sensitive to high temperatures and that the maximum amount of nitrogen

introduced into titania lattices is quite limited. In recent years, p-n codoping with anion and cation pairs has been proposed in order to offer charge compensation opportunities that minimise crystallographic defects [14–17]. One of the most promising semiconductor amongst the p-n codoped titanias is W(n-type dopant), N(p-type dopant) codoped anatase TiO₂. Improved photonic efficiencies and selectivity for various semiconductor-sensitised photoreactions have been reported [18–20]. Despite such experimental evidence, a clear and complete picture of the fundamental mechanisms for their photoactivity is far from being understood. A significant lack of detailed microscopic information about the effect of the codoping on the structure and electronic properties of TiO₂ has yet to be filled. A few attempts to resolve crystal and band structures through computational studies exist [21,17], however these simulations are not representative of all the possible structures. For example, computed band structures and density of states often refer to substitutional N and substitutional W, however in many cases

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interstitial N predominates over the substitutional, making calculations and simulations more complex and highly demanding from a computational point of view. We attempt here to provide an experimental approach to this problem. Specifically, we adopt a combination of electrochemical impedance spectroscopy, UV-vis spectroscopy and electron paramagnetic resonance spectroscopy to measure redox potentials of band edges and intraband gap states, optical band gaps and characterise the photochemistry (including exciton formation and trapping under visible-light illumination) of a (W,N) codoped TiO₂ semi-conductor, with the final goal of elucidating a structure-photochemistry relationship.

2. Experimental

(W,N)-codoped TiO₂ containing 0.1 at.% of W was synthesised using a sol-gel route as described in details in one of our previous papers [22]. Mineralogy and crystallinity were interrogated by X-ray diffraction (XRD). XRD patterns were obtained using a Bruker D8 Advance diffractometer equipped to deliver CuK α X-ray radiation (1.54 Å) at room temperature. Optical absorption investigation was conducted using a modular UV-vis diffuse reflectance spectrometer StellarNet EPP2000. Spectra were processed according to the Kubelka-Munk transform/Tauc plot approach for indirect semiconductors in order to derive information about optical band gaps.

Electrochemical impedance spectroscopy (EIS) measurements were performed using a three-electrode cell consisting of: the (W,N)-codoped TiO₂ sample coated onto a FTO glass slide as a working electrode, a coiled platinum wire counter electrode, and an Ag/AgCl reference electrode (3 mol/L NaCl, + 205 mV vs SHE). The electrodes were fixed in the measurement cell in a way that only the coated part of the FTO glass (circular contact area of 1.77 cm²) was in contact with the 0.1 mol/L H₂SO₄ electrolyte (more details about the preparation of the coated FTO slides can be found on [33]). Impedance spectra were collected with the use of a Zahner IM6e potentiostat in the potential range of 1.30 V to 0.0 V vs SHE with 25 mV steps. Each spectrum (i.e. at a fixed potential) was recorded in a frequency range of 1×10^5 Hz to 1×10^{-1} Hz with 11 steps per decade and an amplitude of 10 mV. The spectra were subsequently fitted to a Randles circuit (used as an equivalent circuit to represent a simple electrode/electrolyte interface, insets in Fig. 3) to derive the values for the space charge layer capacitance (CSC). In the equivalent circuit, a constant phase element (CPE) replaces the ordinary double layer capacitance (CSC) to simulate an uneven surface of the material. The exponential parameter of the CPE was found to be between 0.95 and 1.00, indicating almost ideal capacitance behaviour. Consequently, the space charge layer capacitance was assumed equal to the pseudocapacitance of the CPE. A Mott-Schottky plot was then constructed for each semiconductor oxide by plotting the inverted square of the space charge layer capacitance normalised for the contact area against the potential at which the (CSC) was derived.

EPR spectra were recorded with a JEOL JES-FA200 spectrometer operating either at 77 K with liquid N₂ or at 4 K with liquid He. Before each measurement, the samples were evacuated at room temperature and under high vacuum, ca. 10⁻⁶ bar. Spectra were recorded in darkness and under in situ irradiation (in the spectrometer cavity) with an Oriel 500 W Xe arc light source, filtered using a 550 nm band-pass filter (Andover Corporation, 550FS80-50 (Q097-05)).

3. Results and discussion

Fig. 1 shows the X-ray diffraction pattern of the (W,N)-codoped TiO₂ containing 0.1 at.% of W together with the pattern of a pure anatase; no crystalline phases other than anatase were detectable in the doped sample. Diffuse reflectance UV-vis spectra of the N- and W-codoped samples (Fig. 2a) are typical of anatase but with an additional feature emphasised in the Tauc plots (Fig. 2b) for the codoped samples, corresponding to an energy gap (extrinsic band gap) of 2.32 eV ± 0.02 eV

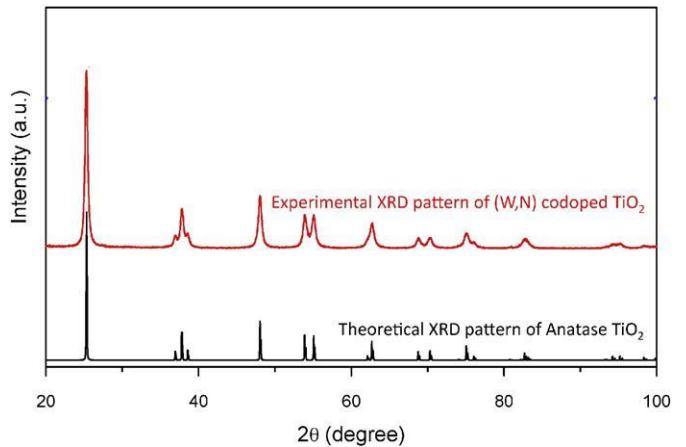
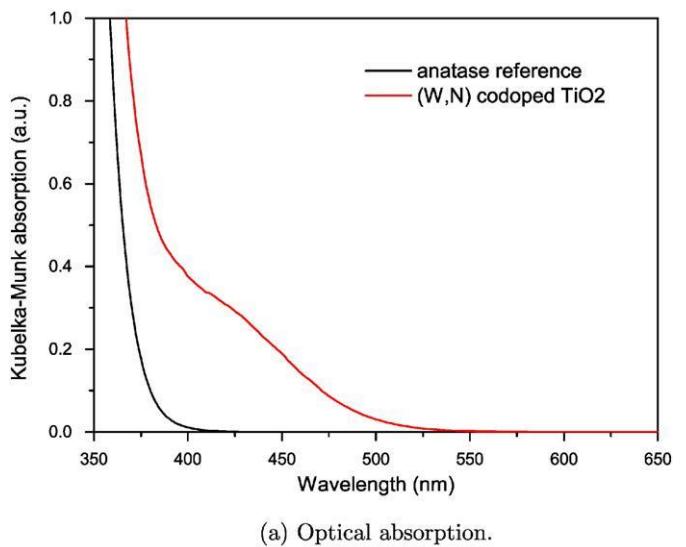
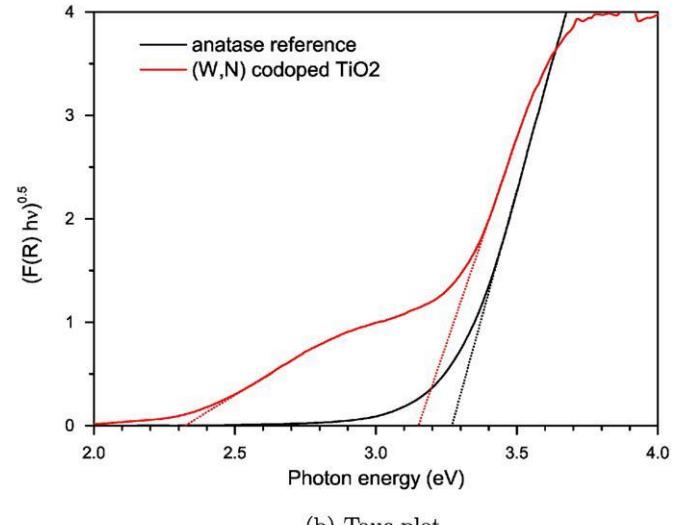


Fig. 1. XRD pattern of (W,N)-codoped TiO₂. The theoretical XRD pattern of anatase TiO₂ is reported as a reference.

and likely to be associated with an electronic transition from an intra-band-gap state due to the presence of N doping [22,9] to the conduction band. This transition is responsible for the observed pale yellow colour



(a) Optical absorption.

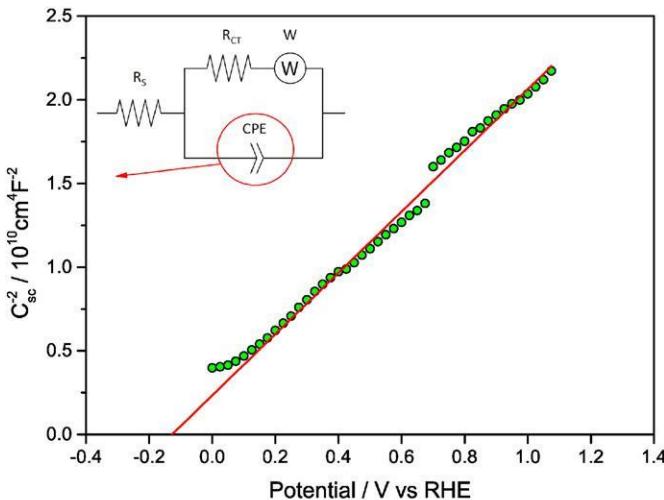


(b) Tauc plot.

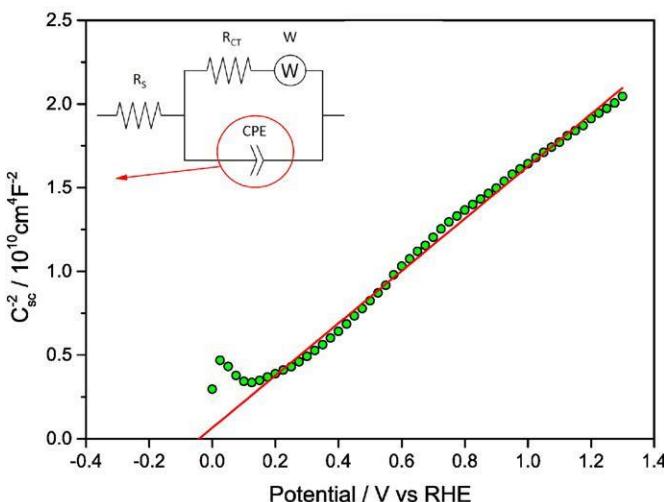
Fig. 2. Optical absorption spectrum and Tauc plot of (W,N)-codoped TiO₂. The spectrum and Tauc plot of anatase TiO₂ are reported as a reference.

of the material. The measured intrinsic and extrinsic absorption edges are neither corrected for the phonon energy involved with the indirect transition nor for the exciton binding energy. However, in the case of TiO₂ these quantities are on the order of thousandths of an electron-volt [23]. They are smaller than the average error on the measurement being on the order of hundredths of an electron-volt, and can therefore be neglected. After irradiation with broad band light (UV-A + vis) the (W,N)-codoped TiO₂ assumes a blue colour, which intensity is enhanced if the material is irradiated in the presence of a hole scavenger. This is the result of a new absorption event occurring between 750 nm to 1000 nm and could be associated with the presence of either Ti³⁺ or W⁵⁺ traps deep in the band gap. With solely UV-vis data, it is not possible to assert either of the reduced metal centres. The nature of the paramagnetic species associated with this absorption event should be interrogated in order to discriminate between the two possible trapping centres. We will elaborate on this point further below in the discussion.

The conduction band edge is derived using electrochemical impedance spectroscopy (EIS) measurements. A Mott–Schottky plot is constructed as reported in Fig. 3 by plotting the inversed square of the



(a) Mott-Schottky replicate 1.



(b) Mott-Schottky replicate 2.

Fig. 3. Mott–Schottky plots of (W,N)-codoped TiO₂. The individual data points are extrapolated to the x-axis using linear regression (red line). a and b are two replicates of the same sample, then averaged.

space charge layer capacitance normalised for the contact area against the potential at which the CSC is derived. The extrapolation of the linear trend in the Mott–Schottky plot to the x-axis (potential) leads to the quantity δU_{fb} \propto $k_{\text{B}} T_p$ (see Eq. (1)) from which the flat band potential (U_{fb} , also representing the Fermi level since there is no band bending at flat band conditions) for a given semiconductor oxide could be derived [24–26].

$$\frac{2}{\delta C_{sc} \beta^{-2} / \epsilon_0 \epsilon_{nd} U - U_{fb}} = \frac{k_B T}{e} : \delta I_P$$

Additionally, the donor density n_d is calculated from the slope of the linear part using a value of 41 for the dielectric constant of anatase [27]. As the donor density was found higher ($\geq 1 \times 10^{20} \text{ cm}^{-3}$) than the effective density of states in the conduction band ($2.42 \times 10^{19} \text{ cm}^{-3}$) assuming a value of $1.0m_e$ for the electron effective mass [28,29], the energy difference between Fermi level and conduction band edge is very small ($b k_{\text{B}} T \approx 25 \text{ mV}$) and they can be assumed to be approximately the same ($U_{cb} \approx U_{fb}$) and equal to $-0.06 \text{ V} \pm 0.03 \text{ V}$ vs RHE (average of the two Mott–Schottky plots in Fig. 3), defining the positions of the valence band edge and intra-band-gap edge at $+ 3.09 \text{ V} \pm 0.06 \text{ V}$ and $+ 2.26 \text{ V} \pm 0.05 \text{ V}$ respectively (see intrinsic and extrinsic band gaps above). A schematic diagram of the band structure is given in Fig. 4-a.

The lower part of Fig. 4b shows the EPR spectra measured at 77 K in the region of the free electron. The EPR signal recorded can be described as a combination of three different EPR active centres, all associated to N-based species (Fig. 5) [22]. A first paramagnetic centre, b1, can be attributed to adsorbed molecular NO [10,4] often detected in the cavities of sol-gel N-TiO₂ [4]. This species exhibits an anisotropic g tensor with rhombic symmetry, $g_{xx} \neq g_{yy} \neq g_{zz}$. The coupling of the unpaired electron with ¹⁴N (nuclear spin I = 1; signal multiplicity $2I + 1 = 3$) develops a hyperfine structure characterised by 3×3 lines. g and A tensors are:

g 2 1:998 3 A¹⁴N 2 32:0 3 Gauss
 $\frac{1}{4}$ 2:003 1:927 7 $\frac{1}{4}$ b1:0 9:6 $\frac{1}{2}$ &
 4 5 4 5

A second paramagnetic centre, b2, consists of an interstitial N chemically bound to a lattice O ion forming a $[NiO]^\bullet$ [30] group carrying one electron in the singly occupied molecular orbital (SOMO). $[NiO]^\bullet$ is an intra-band gap NO^2 state also exhibiting an anisotropic g tensor with rhombic symmetry [30,4,3,22]:

A third paramagnetic centre, b3, is present which we showed being generated by a close range interaction of paramagnetic NO^2 with W, $[\text{NiO}]_w$ [22]. The signal is the combination of two contributions; one for the four EPR equivalent isotopomers associated with the W zero nuclear spin nuclides, i.e. $^{180}_{\text{74}}\text{W}$, $^{182}_{\text{74}}\text{W}$, $^{184}_{\text{74}}\text{W}$ and $^{186}_{\text{74}}\text{W}$ (effectively the same as b2 however distorted due to the surrounding lattice W, Fig. 6a); a second one for the isotopomer associated with $^{183}_{\text{74}}\text{W}$ that is able to generate super hyperfine splitting as the electron in the NO^2 SOMO couples with the $^{183}_{\text{74}}\text{W}$ 1/2-spin nucleus (Fig. 6b). The component b3' without super hyperfine splitting is described by:

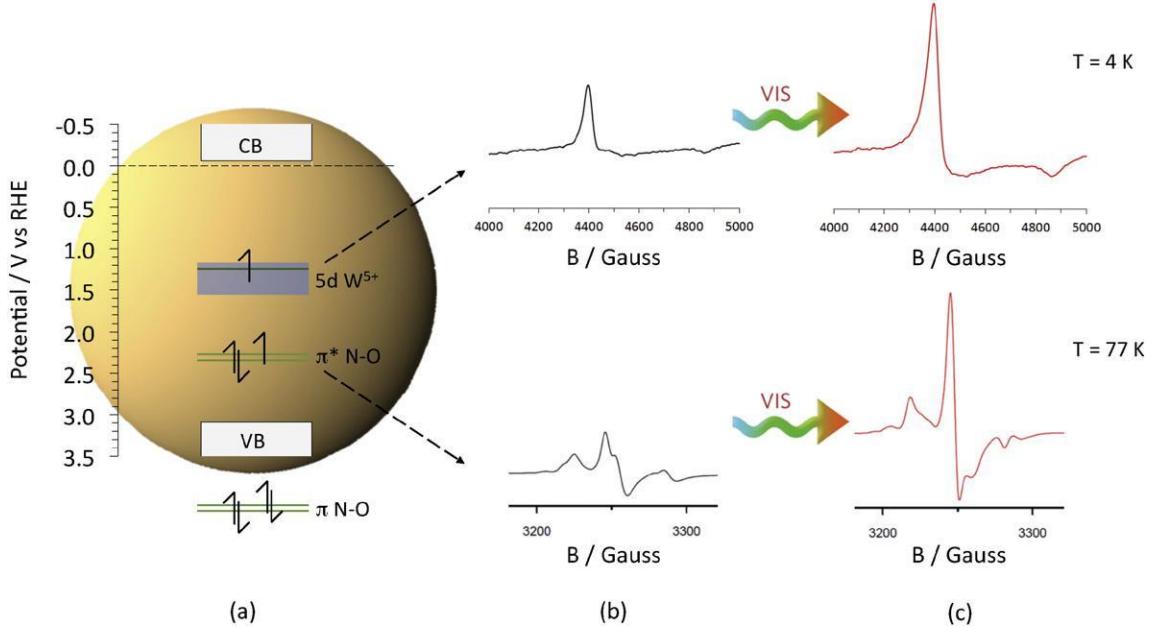


Fig. 4. (a) Band structure diagram of (W,N)-codoped TiO₂ containing 0.1 at.% of W. (b) CW X-band Electron Paramagnetic Resonance spectra before in-situ irradiation with 550 nm wave-length light and (c) CW X-band Electron Paramagnetic Resonance spectra after in-situ irradiation with 550 nm wavelength light. EPR signals related to the N-based species and W-based species were recorded at different ranges of magnetic field (due to the very distinckted g-values) and at different temperature, i.e. 77 K for the N-based species and 4 K for W⁵⁺. The much lower temperature necessary for detecting W⁵⁺ with EPR is due to the too short relaxation time at 77 K.

whilst the component of b3'' with super hyperfine splitting accounting for 14.31%, i.e. the abundance of ⁷⁴¹⁸³W, by:

g	2 2:001 3	A ¹⁴ N ₇	2 8:0 3	Gauss A ¹⁸³ W ⁷⁴	2b1:0 3 Gauss :
	2:002		8:0	& 74	16:0
1/4	7	1/4	1/2		1/2 &
4 2:000 5		4 50:0 5		422:0 5	

In this region, there seems to be no evidence for the presence of Ti³⁺, that – if present in the semiconductor oxide – should be visible at 77 K in this range of magnetic field [31]. On the contrary when the temperature is lowered to 4 K in liquid He, a new anisotropic g tensor with axial

symmetry, g_⊥ ≠ g_{||}, appears at higher magnetic fields (upper part of Fig. 4b), which components are:

$$g_{1/4} \begin{matrix} 1:477 \\ 1:342 \end{matrix}$$

The position of this signal is in agreement with a similar signal previously recorded by Zhao et al. [32] for W⁵⁺ in WO₃/TiO₂ mixed oxide system. g components of octahedral W⁵⁺ are significantly lower than the ones of isoelectronic d1 ions like Mo⁵⁺ or V⁴⁺. This is due to a greater spin-orbit coupling for tungsten [34]. The presence of W⁵⁺ before illumination can be explained through charge compensation mechanisms. W⁶⁺ is replacing Ti⁴⁺ ions in the TiO₂ lattice. The excess of positive charges clearly needs to be compensated by corresponding negative ones. There are three possible mechanisms for compensating the extra positive charges carried by W⁶⁺: ionic, electronic and comple-mentary doping, Eqs. (2)–(4) respectively.

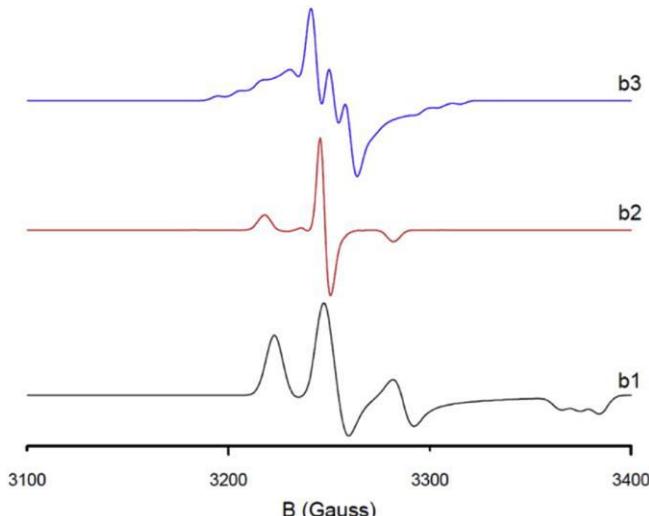
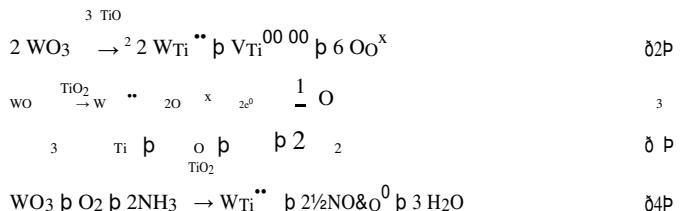
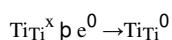


Fig. 5. Simulated single spectra of the three EPR active centres b1, b2 and b3. b1 corresponds to an adsorbed molecular paramagnetic NO; b2 corresponds to an interstitial N chemically bound to a lattice O ion forming a [NiO] group carrying one electron in the singl-y occupied molecular orbital (SOMO); b3 is a the species chemically equivalent to b2 but influenced by a short-range interaction with W. The intensities in this figure are relative to the components alone. The combination (with different relative contributions) of the spectra b1, b2, and b3 make up for the overall spectra on the lower parts of Fig. 4-b and c [22].



All the three mechanisms can be simultaneously present (albeit for low W doping the compensation with N seems to be the favourite one [33]). The electronic charge compensation (i.e. formation of free elec-trons, Eq. (3)) would lead to a noticeable increase in the donor density of the materials. However, electrochemical impedance spectroscopy for this codoped system showed no significant variation in the donor density when compared to undoped anatase TiO₂. A possible interpre-tation for this is that if charge compensating electrons are formed, they are trapped in energetically favourable states:



δ5P

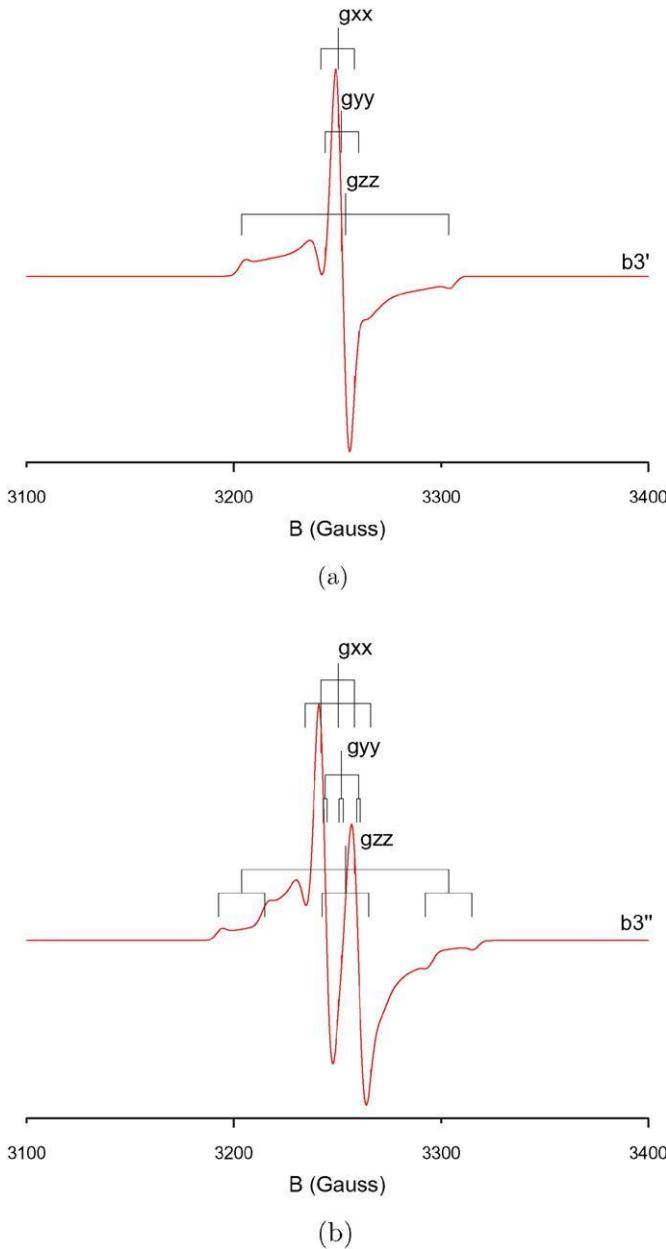


Fig. 6. Simulated single EPR profiles of: (a)-b3' four equivalent $\frac{1}{2}\text{NiO}_{\&x;}\text{W}$ paramagnetic isotopomers carrying a null spin ${}^x\text{W}$ nuclide, $x = 180, 182, 184, 186$; (b)-b3'' $\frac{1}{2}\text{NiO}_{\&183;\text{W}}$ paramagnetic isotopomer carrying ${}^{183}\text{W}$ nuclide, $I = 1/2$.



The absence of Ti^{3+} (TiTi^0 in Kröger–Vink notation) in the EPR spectra but the clear presence of W^{5+} (WTi in Kröger–Vink notation) would suggest a more energetically favourable (i.e. deeper in the band gap) trapping of the compensating electrons as reduced tungsten.

Having identified the nature of the EPR active species, we can now explain the spectral changes when the sample is irradiated with visible light (550 nm wavelength) (Fig. 4c) which are a consequence of the electron dynamics within the structure of the doped semiconductor. As in the case of N doping only, a large fraction of the nitrogen centres is diamagnetic before light irradiation, carrying two paired electrons in the highest occupied molecular orbital. They can be seen as a $[\text{NiO}]^-$, intra-band gap NO^3 states [9], and similarly, $[\text{NiO}]^W$ and intra-

band gap NO^3 states characterised by close range N–W coupling. The dark spectrum is therefore dominated by the signal of adsorbed molecular NO [10,4] (b1 centre). Upon irradiation with visible light, electron transitions CB NO^3 occur, leaving behind a much larger quantity of paramagnetic NO^2 states that can be easily detected by EPR. The signal of the adsorbed molecular NO does not significantly change but the considerable formation of paramagnetic $[\text{NiO}]^*$ and $[\text{NiO}]^W$ centres is responsible for the new profile of the EPR spectrum (lower part of Fig. 4c) together with the increased intensity. After switching the light off (spectrum not reported here), the intensity of the $[\text{NiO}]^*$ and $[\text{NiO}]^W$ signals decreases very slowly whilst, once again, the component assigned to the adsorbed molecular NO does not show a significant change. However, even after more than 30 min in the dark, the overall spectrum is still dominated by the $[\text{NiO}]^*$ and $[\text{NiO}]^W$ centres and the initial spectrum before irradiation not recovered. As far as W^{5+} signal is concerned (upper part of Fig. 4c), it is evident how the signal intensity increases upon irradiation with visible light. On the basis of this spectral change, it is assumed that the electrons excited from the NO^{3-} states to the conduction band fall into W^{5+} trapping state, effectively reducing more lattice W^{6+} to W^{5+} . The electron trapping process is expected to be maximum under the conditions adopted given in the absence of electron scavengers in the EPR cell. Furthermore, we can now assert with a sufficient degree of confidence that the optical absorption event observed at 750 nm to 1000 nm after light irradiation (hence

after quantitative formation of W^{5+} states), should be attributed to $\text{CB} \leftarrow \text{W}^{5+}$ transitions.

4. Conclusions

The coupling of electrochemical impedance spectroscopy with other spectroscopic techniques such as UV-vis and electron paramagnetic resonance proved to be an effective approach to obtain useful information about semiconductor band structure, including band edge and intra-band gap state redox potentials, and follow photon-induced charge carriers dynamics. This approach has been described here using a (W,N) codoped TiO_2 semiconductor as a testing material.

The simultaneous presence of W and N causes a shift in the potential of the conduction band edge; from -0.2 V versus RHE for the undoped anatase TiO_2 to -0.06 V versus RHE, effectively narrowing the intrinsic band gap by about 0.12 eV when compared to the 3.27 eV here measured for the undoped anatase TiO_2 .

Upon irradiation with green light (550 nm) paramagnetic intra-band gap species $[\text{NiO}]^*$ and $[\text{NiO}]^W$ (formally NO^2) are photo-generated as a consequence of photon absorption and electronic transitions from diamagnetic donor states $[\text{NiO}]^-$, and $[\text{NiO}]^-W$ (formally NO^3) to the TiO_2 conduction band. The optical transition from the NO^3 intra-band gap states to the conduction band was measured around 2.32 eV. In the absence of effective electron scavengers, conduction band electrons are preferentially trapped as reduced tungsten, W^{5+} , as experimental evidences show that these trapping states should be located at lower energy than Ti^{3+} traps commonly found in undoped TiO_2 semiconductors.

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